



Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638
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**SDR9JF thru SDR9MF
 and
 SDR9JFSMS thru SDR9MFSMS
 Series**

Designer's Data Sheet

Part Number/Ordering Information ^{1/}

SDR9

 |
 | **Screening ^{2/}**
 | = Not Screened
 | TX = TX Level
 | TXV = TXV
 | S = S Level
 |
 | **Package Type**
 | = Axial Leaded
 | SMS = Surface Mount Square Tab
 | ASMS = SMS with .145/.155" End Tab Size
 |
 | **Voltage/Family**
 | JF = 600V
 | KF = 800V
 | MF = 1000V

**9.0 AMPS
 600 – 1000 VOLTS
 250 ns typical FAST RECOVERY
 RECTIFIER**

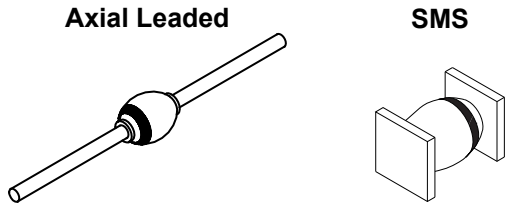
- FEATURES:**
- Fast Reverse Recovery: 250ns Maximum ^{4/}
 - PIV to 1000 Volts
 - Hermetically Sealed
 - Low Reverse Leakage Current
 - Single Chip Construction
 - Replaces Larger DO-4 Rectifiers
 - Low Thermal Resistance
 - Available in Axial & Square Tab Versions
 - TX, TXV, and S-Level Screening Available ^{2/}
 - Ultra Fast and Hyper Fast Recovery Versions Available- Contact Factory

MAXIMUM RATINGS ^{3/}

| RATING | SYMBOL | VALUE | UNIT |
|--|--|--|-----------------------------|
| Peak Repetitive Reverse Voltage And DC Blocking Voltage | SDR9JF & SDR9JFSMS SDR9KF & SDR9KFSMS SDR9MF & SDR9MFSMS | V _{RRM} V _{RWM} V _R | 600 800 1000 Volts |
| Average Rectified Forward Current (Resistive Load, 60Hz, Sine Wave, T _A = 25°C) | I _O | 9.0 | Amps |
| Peak Surge Current (8.3 ms pulse, half sine wave, superimposed on I _O , allow junction to reach equilibrium between pulses, T _A = 25°C) | I _{FSM} | 100 | Amps |
| Operating & Storage Temperature | T _J and T _{STG} | -65 to +175 | °C |
| Thermal Resistance | Junction to Lead for Axial, L = .125" Junction to End Tab for Surface Mount | R _{θJL} R _{θJE} | 8 4 °C/W |

NOTES:

- 1/** For Ordering Information, Price, Operating Curves, and Availability- Contact Factory.
2/ Screening Based on MIL-PRF-19500. Screening Flows Available on Request.
3/ Unless Otherwise Specified, All Electrical Characteristics @25°C.
4/ I_F = 500mA, I_R = 1A, I_{RR} = 250mA, T_A = 25°C





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| ELECTRICAL CHARACTERISTICS ^{3/} | | | | |
|--|----------------------------|---------------|----------------------|---------------|
| CHARACTERISTICS | | SYMBOL | VALUE | UNIT |
| | | | MAX | |
| Instantaneous Forward Voltage Drop $I_F = 9.0 \text{ Adc}, 300\text{-}500\mu\text{s pulse}$ | $T_A = +25^\circ\text{C}$ | V_{F1} | 1.15 | Vdc |
| | $T_A = -55^\circ\text{C}$ | V_{F2} | 1.30 | |
| Reverse Leakage Current Rated V_R , 300 μs pulse minimum | $T_A = +25^\circ\text{C}$ | I_{R1} | 1.0 | μA |
| | $T_A = +100^\circ\text{C}$ | I_{R2} | 50 | |
| Junction Capacitance $V_R = 10 \text{ Vdc}, f = 1\text{MHz}, T_A = 25^\circ\text{C}$ | | C_J | 50 | pF |
| Reverse Recovery Time $I_F = 500\text{mA}, I_R = 1\text{A}, I_{RR} = 250\text{mA}, T_A = 25^\circ\text{C}$ | | t_{rr} | 250 typ. 325 max. | ns |

Package Outlines:

| DIMENSIONS (inches) | | | DIMENSIONS (inches) | | |
|---------------------|---------|---------|---------------------|---------|---------|
| DIM. | Minimum | Maximum | DIM. | Minimum | Maximum |
| A | --- | .170 | A (SMS) | .170 | .180 |
| B | .210 | .250 | A (ASMS) | .145 | .155 |
| C | .037 | .043 | B | .260 | .300 |
| D | 1.000 | --- | C | .020 | .030 |
| | | | D | .002 | --- |
| AXIAL | | | SMS | | |
| | | | | | |

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RC0056E

DOC